NSN 5961-01-096-7853

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View Online at https://aerobasegroup.com/nsn/5961-01-096-7853 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Overall Height:** 0.225 inches **Overall Width:** 0.425 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter voltage, dc with base short-circuited to emitter and 3.5 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 06845-4042879 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon and 1 case Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

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